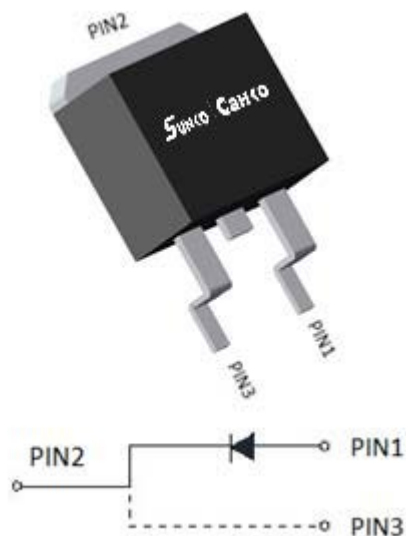


Ultra-Fast Recovery Diodes 8A FRED



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-263
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURB8120
Device marking code			MURB8120
Repetitive Peak Reverse Voltage	V _{RRM}	V	1200
Average Rectified Output Current @60Hz sine wave, R-load, Tc(FIG.1)	I _O	A	8
Surge(Non-repetitive) Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	I _{FSM}	A	60
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s	14.94
Storage Temperature	T _{stg}	°C	-55 ~ +150
Junction Temperature	T _j	°C	-55 ~ +150
Junction capacitance @4V, 1MHz	C _j	pF	26

MURB8120

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	$I_{FM}=8.0A$ @ $T_J=25^{\circ}C$	-	2.00	2.50
			$I_{FM}=8.0A$ @ $T_J=125^{\circ}C$		1.70	2.10
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	μA	$V_{RM}=V_{RRM}$ $T_J=25^{\circ}C$	-	-	5.0
	I_{RRM2}		$V_{RM}=V_{RRM}$ $T_J=125^{\circ}C$	-	-	200
Reverse Recovery Time	T_{rr}	ns	$I_F=0.5A$ $I_{RM}=1A$ $I_{RR}=0.25A$ $T_J=25^{\circ}C$	-	44	75
			$T_J=25^{\circ}C$	-	249	-
			$T_J=125^{\circ}C$	-	438	-
Peak recovery current	I_{RRM}	A	$T_J=25^{\circ}C$	-	5.18	-
			$T_J=125^{\circ}C$	-	7.32	-
Reverse recovery charge	Q_{rr}	nC	$T_J=25^{\circ}C$	-	645	-
			$T_J=125^{\circ}C$	-	1555	-

■Thermal Characteristics ($T_J=25^{\circ}C$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MURB8120
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^{\circ}C/W$	2.0
	Between junction and Air	$R_{\theta J-A}$	$^{\circ}C/W$	50

■Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MURB8120	Approximate 1.43	50	2000	8000	Tube
MURB8120	Approximate 1.43	1000	2000	10000	Reel

■ Characteristics (Typical)

FIG1: I_o - T_c Curve

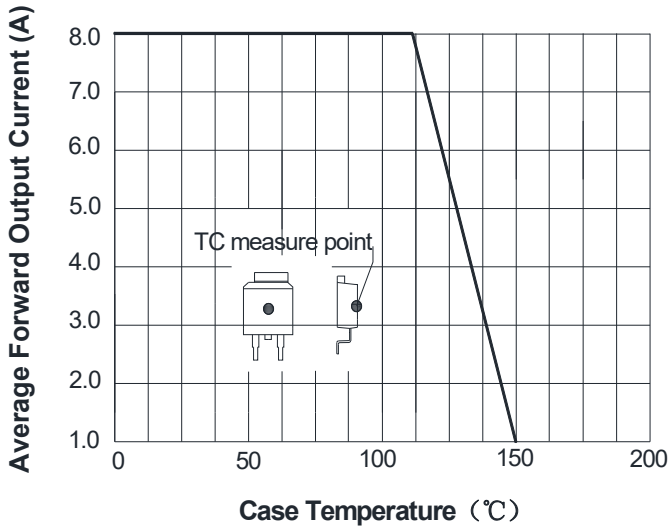


FIG2: Surge Forward Current Capability

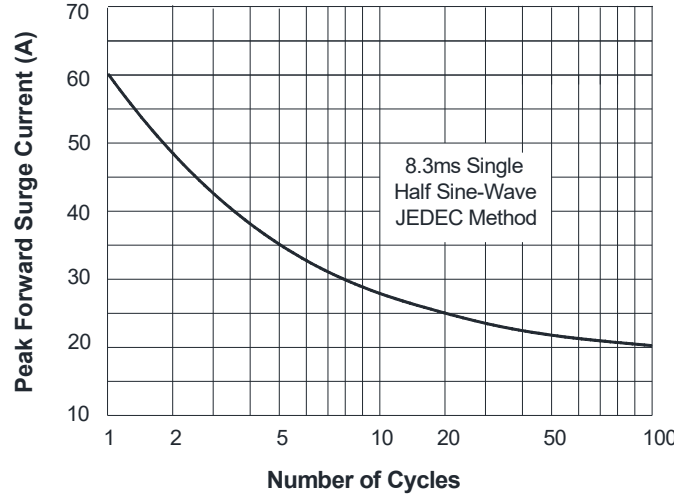


FIG3: Forward Voltage

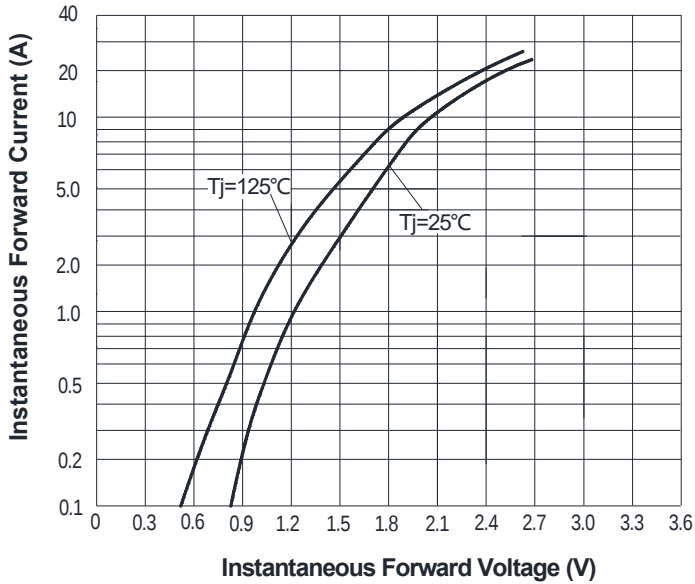
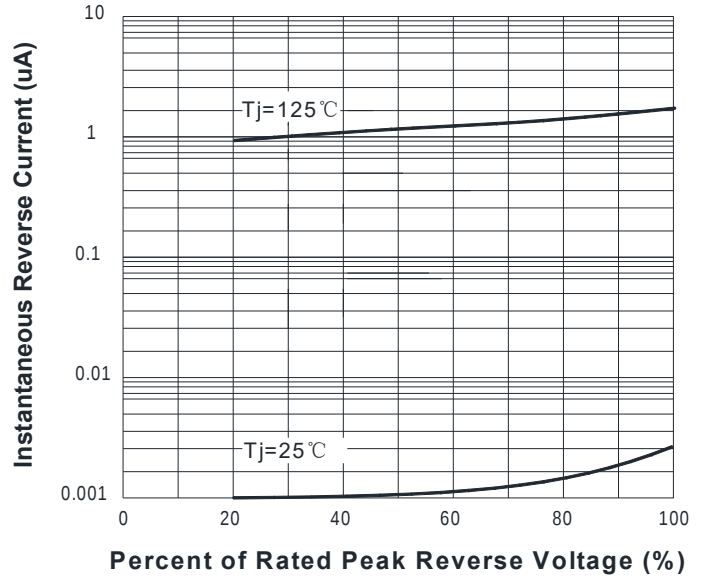
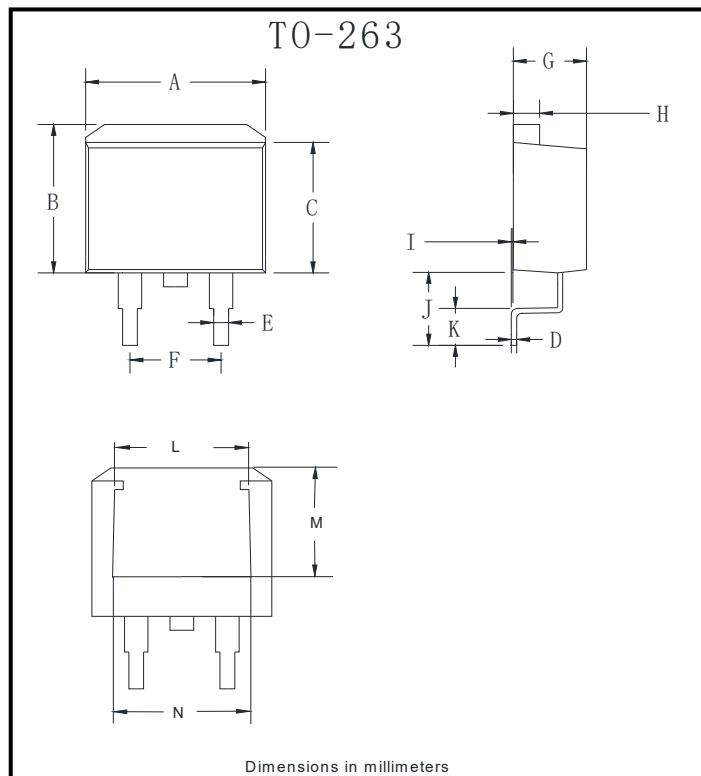


FIG4: Instantaneous Reverse Characteristics

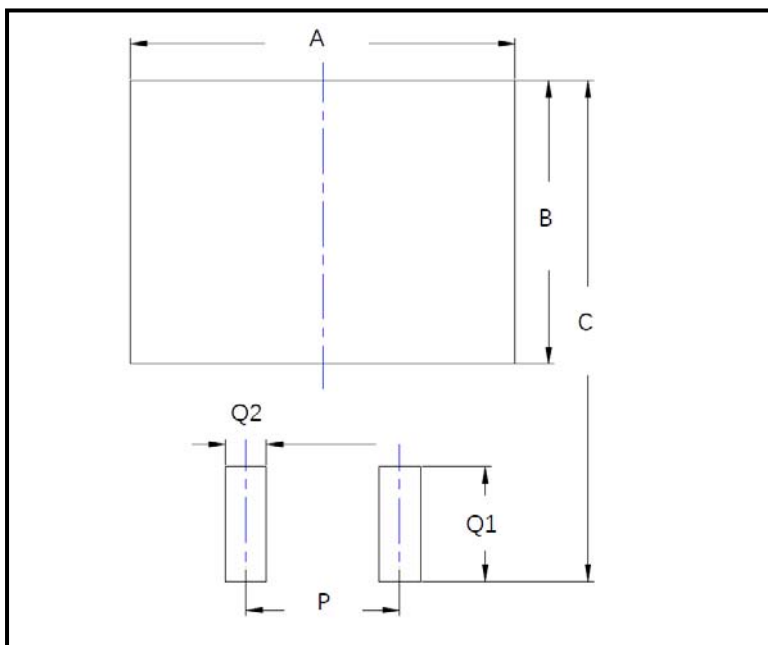


■ **Outline Dimensions**



TO-263		
Dim	Min	Max
A	9.85	10.45
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.4	4.8
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ **Suggested Pad Layout**



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35

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